New Product



Vishay General Semiconductor

High Current Density Surface Mount Schottky Barrier Rectifiers



K Anode 1 Cathode Anode 2

PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 4.0 A				
V _{RRM}	20 V, 30 V				
I _{FSM}	120 A				
E _{AS}	20 mJ				
V_F at $I_F = 4 A$	0.41 V				
T _J max.	150 °C				

TYPICAL APPLICATIONS

For use in low voltage high frequency inverters, freewheeling, dc-to-dc converters, and polarity protection applications.

FEATURES

- Very low profile typical height of 1.1 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency
- Low thermal resistance
- Meets MSL level 1, per J-STD-020
- AEC-Q101 qualified
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21
 definition

MECHANICAL DATA

Case: TO-277A (SMPC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free and RoHS compliant, commercial grade

Base P/NHM3 - halogen-free and RoHS compliant, automotive grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test, HM3 suffix meets JESD 201 class 2 whisker test

MAXIMUM RATINGS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	SS8P2CL	SS8P3CL	UNIT		
Device marking code		S82CL	S83CL			
Maximum repetitive peak reverse voltage	V _{RRM}	20	30	V		
Maximum average forward rectified current (fig. 1) total device per diode	I _{F(AV)}	8.0 4.0		А		
Peak forward surge current 10 ms single half sine-wave superimposed on rated load per diode	l I _{FSM}	120		А		
Non-repetitive avalanche energy at 25 °C, $I_{AS} = 2$ A per diode	E _{AS}	20		mJ		
Operating junction and storage temperature range	T _{J,} T _{STG}	- 55 to + 150		°C		

Document Number: 89030 Revision: 24-Nov-09 For technical questions within your region, please contact one of the following: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com FREE

AUTOMOTIVE

Available



SS8P2CL, SS8P3CL

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ELECTRICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode ⁽¹⁾	I _F = 2.0 A I _F = 4.0 A	T _A = 25 °C	V _F	0.42 0.50	- 0.54	v
	I _F = 2.0 A I _F = 4.0 A	T _A = 125 °C		0.32 0.41	- 0.45	
Reverse current per diode ⁽²⁾	Rated V _R	T _A = 25 °C T _A = 125 °C	I _R	48 19	300 30	μA mA
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	250	-	pF

Notes

 $^{(1)}$ Pulse test: 300 μs pulse width, 1 % duty cycle

⁽²⁾ Pulse test: Pulse width \leq 40 ms

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	SS8P2CL	SS8P3CL	UNIT		
Typical thermal resistance per diode	${\sf R}_{ heta JA} ^{(1)} \ {\sf R}_{ heta JL}$	60 3		°C/W		

Note

⁽¹⁾ Units mounted on recommended P.C.B. 1 oz. pad layout

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
SS8P3CL-M3/86A	0.10	86A	1500	7" diameter plastic tape and reel		
SS8P3CL-M3/87A	0.10	87A	6500	13" diameter plastic tape and reel		
SS8P3CLHM3/86A (1)	0.10	86A	1500	7" diameter plastic tape and reel		
SS8P3CLHM3/87A (1)	0.10	87A	6500	13" diameter plastic tape and reel		

Note

⁽¹⁾ Automotive grade

New Product



SS8P2CL, SS8P3CL

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RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

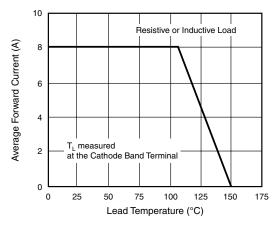


Figure 1. Maximum Forward Current Derating Curve

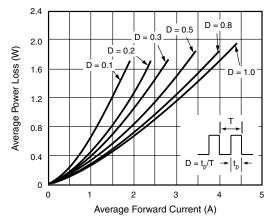


Figure 2. Forward Power Loss Characteristics Per Diode

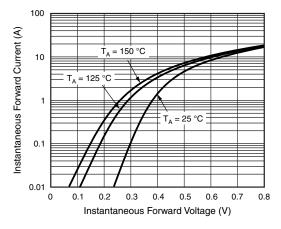


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

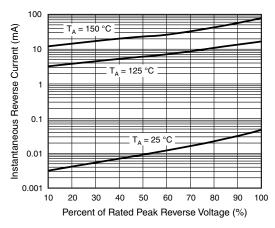


Figure 4. Typical Reverse Leakage Characteristics Per Diode

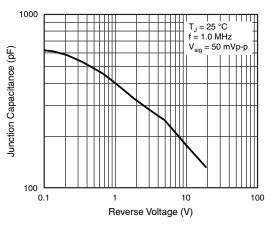
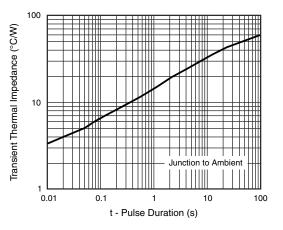
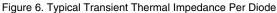


Figure 5. Typical Junction Capacitance Per Diode





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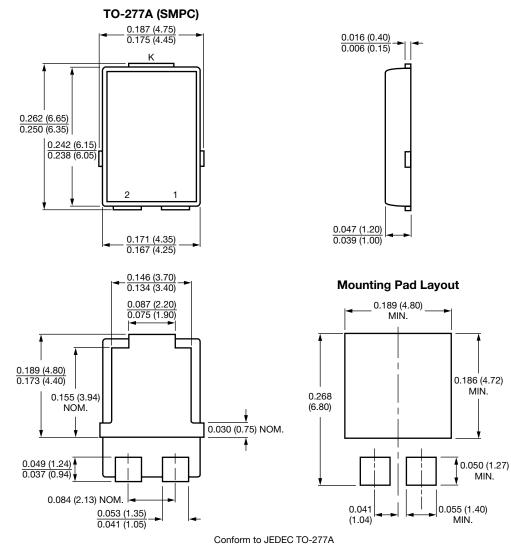
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SS8P2CL, SS8P3CL

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PACKAGE OUTLINE DIMENSIONS in inches (millimeters)



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